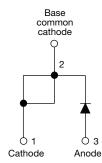


**Vishay Semiconductors** 

## HEXFRED<sup>®</sup> Ultrafast Soft Recovery Diode, 15 A



#### TO-247AC modified



PRODUCT SUMMARY						
Package	TO-247AC modified (2 pins)					
I <sub>F(AV)</sub>	15 A					
V <sub>R</sub>	600 V					
V <sub>F</sub> at I <sub>F</sub>	1.2 V					
t <sub>rr</sub> typ.	19 ns					
T <sub>J</sub> max.	150 °C					
Diode variation	Single die					

### FEATURES

- Ultrafast and ultrasoft recovery
- Very low I<sub>RRM</sub> and Q<sub>rr</sub>
- $\bullet$  Designed and qualified according to  ${\sf JEDEC}^{\circledast}{\sf -JESD47}$
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

### DESCRIPTION

VS-HFA15PB60... is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 15 A continuous current, the VS-HFA15PB60... is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I<sub>BRM</sub>) and does not exhibit any tendency to "snap-off" during the th portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA15PB60 ... is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Cathode to anode voltage	V <sub>R</sub>		600	V			
Maximum continuous forward current	I <sub>F</sub>	T <sub>C</sub> = 100 °C	15				
Single pulse forward current	I <sub>FSM</sub>		150	А			
Maximum repetitive forward current	I <sub>FRM</sub>		60				
Movimum nower dissinction	P <sub>D</sub>	T <sub>C</sub> = 25 °C	74	W			
Maximum power dissipation		T <sub>C</sub> = 100 °C	29				
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +150	°C			

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RoHS

COMPLIANT

HALOGEN

FREE



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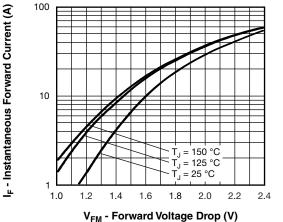
<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J$ = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V <sub>BR</sub>	I <sub>R</sub> = 100 μA		600	-	-	
		I <sub>F</sub> = 15 A		-	1.3	1.7	V
Maximum forward voltage	V <sub>FM</sub>	I <sub>F</sub> = 30 A	See fig. 1	-	1.5	2.0	
	I <sub>F</sub> = 15 A, T <sub>J</sub> = 125 °C			-	1.2	1.6	
Maximum reverse		$V_R = V_R$ rated	See fig. 2	-	1.0	10	
leakage current	I <sub>RM</sub>	$T_J$ = 125 °C, $V_R$ = 0.8 x $V_R$ rated	See fig. 2	-	400	1000	μA
Junction capacitance	CT	V <sub>R</sub> = 200 V	See fig. 3	-	25	50	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from p	ackage body	-	12	-	nH

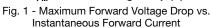
<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CON	TEST CONDITIONS				UNITS
	t <sub>rr</sub>	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}$	4/μs, V <sub>R</sub> = 30 V	-	19	-	
Reverse recovery time See fig. 5, 10	t <sub>rr1</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 15 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 200 V	-	42	60	ns
	t <sub>rr2</sub>	T <sub>J</sub> = 125 °C		-	74	120	
Peak recovery current See fig. 6	I <sub>RRM1</sub>	T <sub>J</sub> = 25 °C		-	4.0	6.0	A
	I <sub>RRM2</sub>	T <sub>J</sub> = 125 °C		-	6.5	10	
Reverse recovery charge See fig. 7	Q <sub>rr1</sub>	T <sub>J</sub> = 25 °C		-	80	180	
	Q <sub>rr2</sub>	T <sub>J</sub> = 125 °C		-	220	600	no
Peak rate of fall of	dl <sub>(rec)M</sub> /dt1	T <sub>J</sub> = 25 °C		-	188	-	A∕µs
recovery current during t <sub>b</sub> See fig. 8	dl <sub>(rec)M</sub> /dt2	T <sub>J</sub> = 125 °C		-	160	-	Λµs

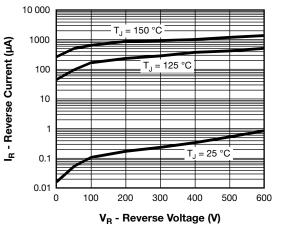
THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	ARAMETER SYMBOL TEST CONDITIONS M					UNITS	
Lead temperature	T <sub>lead</sub>	0.063" from case (1.6 mm) for 10 s	-	-	300	°C	
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	1.7		
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	40	K/W	
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.25	-		
Weight			-	6.0	-	g	
weight			-	0.21	-	oz.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Marking device		Case style TO-247AC modified (JEDEC)	HFA15PB60				



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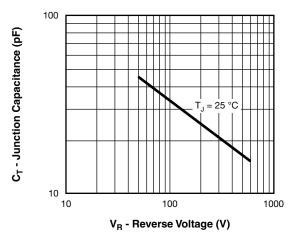
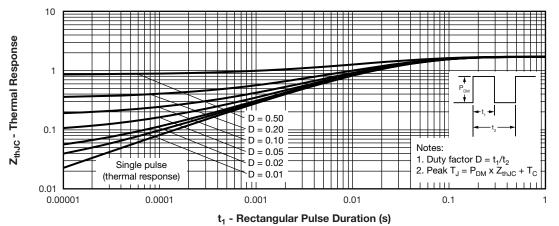
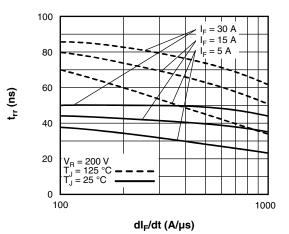


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage









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Fig. 5 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

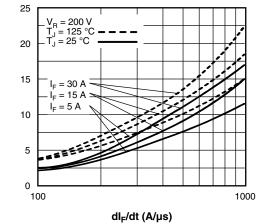
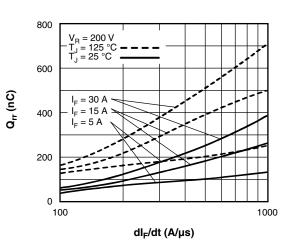
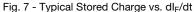


Fig. 6 - Typical Recovery Current vs. dl<sub>F</sub>/dt





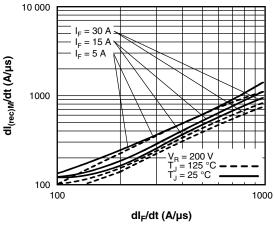


Fig. 8 - Typical dl<sub>(rec)M</sub>/dt vs. dl<sub>F</sub>/dt

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 For technical questions within your region:
 DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com

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I<sub>rr</sub> (A)

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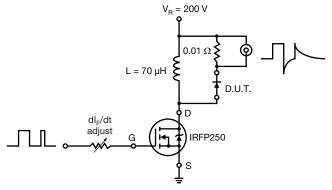
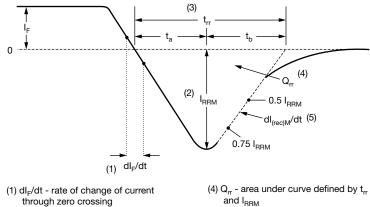


Fig. 9 - Reverse Recovery Parameter Test Circuit



(3) t<sub>rr</sub> - reverse recovery time measured from zero crossing point of negative going  $I_F$  to point where a line passing through 0.75  $\mathrm{I}_{\mathrm{RRM}}$  and 0.50  $\mathrm{I}_{\mathrm{RRM}}$ extrapolated to zero current.

and I<sub>RRM</sub>

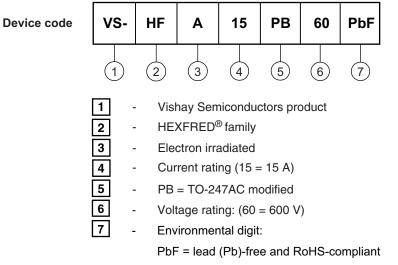
$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

- (5) dl<sub>(rec)M</sub>/dt peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>
- Fig. 10 Reverse Recovery Waveform and Definitions



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#### **ORDERING INFORMATION TABLE**



-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-HFA15PB60PbF	25	500	Antistatic plastic tube					
VS-HFA15PB60-N3	25	500	Antistatic plastic tube					

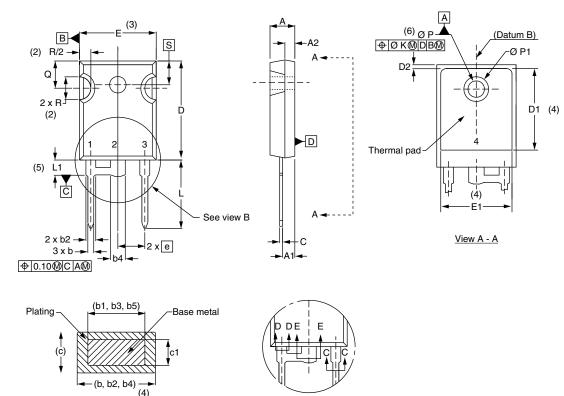
LINKS TO RELATED DOCUMENTS						
Dimensions		www.vishay.com/doc?95541				
Deut es edine : information	TO-247AC modified PbF	www.vishay.com/doc?95225				
Part marking information	TO-247AC modified -N3	www.vishay.com/doc?95442				



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### TO-247AC modified - 50 mils L/F

#### **DIMENSIONS** in millimeters and inches



Section C - C, D - D, E - E

View B
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SYMBOL	MILLIN	IETERS	INCHES		NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.17	1.37	0.046	0.054	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
с	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIMETERS		INCHES		NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
D2	0.51	1.35	0.020	0.053		
E	15.29	15.87	0.602	0.625	3	
E1	13.46	-	0.53	-		
е	5.46 BSC		0.215	BSC		
ØК	0.254		0.010			
L	14.20	16.10	0.559	0.634		
L1	3.71	4.29	0.146	0.169		
ØP	3.56	3.66	0.14	0.144		
Ø P1	-	7.39	-	0.291		
Q	5.31	5.69	0.209	0.224		
R	4.52	5.49	0.178	0.216		
S	5.51	BSC	0.217 BSC			

#### Notes

- <sup>(1)</sup> Dimensioning and tolerance per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- <sup>(4)</sup> Thermal pad contour optional with dimensions D1 and E1
- <sup>(5)</sup> Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- <sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-247 with exception of dimension c and Q

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